# NSN 5961-01-575-9865

Diode Semiconductor Device - Page 1 of 1



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# Voltage Rating In Volts Per Characteristic:

375.0 emitter to collector voltage, floating potential, dc with base biased in reverse direction with respect to the collector not applicable and 400.0 reach through voltage not applicable

# **Capacitance Rating In Picofarads:**

0.1

# **Maximum Operating Tempurature Per Measurement Point:**

175.0 inlet swivel degrees fahrenheit

#### **Product Name:**

Beam lead schottky dc tested diode

#### **Special Features:**

Platinum tri-metal system; silicon nitride passivated; low barrier; packaged 20 units; 20 ohm maximum dynamic reistance; suited for stripline or microline circuits; dc tested; 4 volt min breakdown

#### **Precious Material And Location:**

Leads gold

**Precious Material:** 

Gold

Shelf Life: N/a

**Unit Of Measure:** 

**Demilitarization:** 

No

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